OK In re application of: Chul-Sung Park Group Art Unit: 28/8 not yet assigned Serial No.: October 22, 2003 Examiner: V. NGWG Inot yet assigned Filed: APPARATUS OF REPAIRING MEMORY CELL AND METHOD For: THEREFOR INFORMATION DISCLOSURE CITATION VIET Q. NGUYEN FORM PTO-1449 (Modified) PRIMARY EXAMINER **U.S. PATENT DOCUMENTS** Sub Exam Document Issue Class <u>Class</u> <u>Init</u> Ref Number **Date** <u>Name</u> McClure 10/11/1994 5,355,344 11/28/1998 McClure 5,471,431 5,526,317 6/11/1996 **McClure** 11/25/1997 Liou et al. 5,691,945 5,905,683 5/18/1999 McClure US 6,337,829 B1 1/8/2002 Lee US 6,414,901 7/2002 Shin Sukegawa et al. US 5,689,465 11/1997 Kim US 6,536,002 3/2003 Ooishi et al. US 6,424,582 7/2002 FOREIGN PATENT DOCUMENTS Document Publication .Exam Country **Name** Init Ref <u>Number</u> **Date** 1996-047789 10/23/1996 Korea **OTHER DOCUMENTS** Exam <u>Ref</u> Author, Title, Date, Pertinent Pages, Etc.) <u>Init</u> English Langue of Abstract for Korean Patent Publication No. 1996-047789, filed 10/23/1996.

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